

# NPN Silicon Transistor FJB5555

#### **Features**

- Fast Speed Switching
- Wide Safe Operating Area
- High Voltage Capability
- This is a Pb-Free and Halide Free Device

#### **Applications**

- Electronic Ballast
- Switched Mode Power Supplies

#### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25 °C, unless otherwise noted)

Symbol	Parameter	Value	Unit	
BV <sub>CBO</sub>	Collector-Base Voltage	1050	V	
BV <sub>CEO</sub>	Collector-Emitter Voltage	400	V	
BV <sub>EBO</sub>	Emitter-Base Voltage	14	V	
I <sub>C</sub>	Collector Current (DC)	5	Α	
I <sub>CP</sub>	Collector Current (Pulse)	10	Α	
Ι <sub>Β</sub>	Base Current (DC)	2	Α	
I <sub>BP</sub>	Base Current (Pulse)	4	Α	
$T_J$	Junction Temperature	150	°C	
T <sub>STG</sub>	Storage Junction Temperature Range	-55 to +150	°c	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)

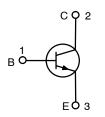
Symbol	Parameter		Value	Unit
P <sub>D</sub>	Total Device Dissipation	ice Dissipation $T_A = 25 ^{\circ}C$		W
		T <sub>C</sub> = 25 °C	100	W
R <sub>θja</sub>	Thermal Resistance, Junction to Ambient (Note 1)		77.75	°C/W
R <sub>θjc</sub>	Thermal Resistance Junction to Case (Note 2)		1.25	°C/W

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- 1. Device mounted on FR-4 PCB, board size = 101.5 mm  $\times$  114.5 mm.
- 2.  $R_{\theta jc}$  test fixture under infinite cooling condition.



D2PAK-3 (TO-263, 3-LEAD) CASE 418AJ



- 1. Base
- 2. Collector
- 3. Emitter

#### **MARKING DIAGRAM**

AWWYZ J5555

A = Assembly Location WW = Work Week

Y = Year

Z = Lot Traceability J5555 = Specific Device Code

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>		
FJB5555TM	D2PAK-3	800 /		
	(TO-263, 3-LEAD)	Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

#### FJB5555

### **ELECTRICAL CHARACTERISTICS** ( $T_C = 25$ °C unless otherwise noted) (Note 3)

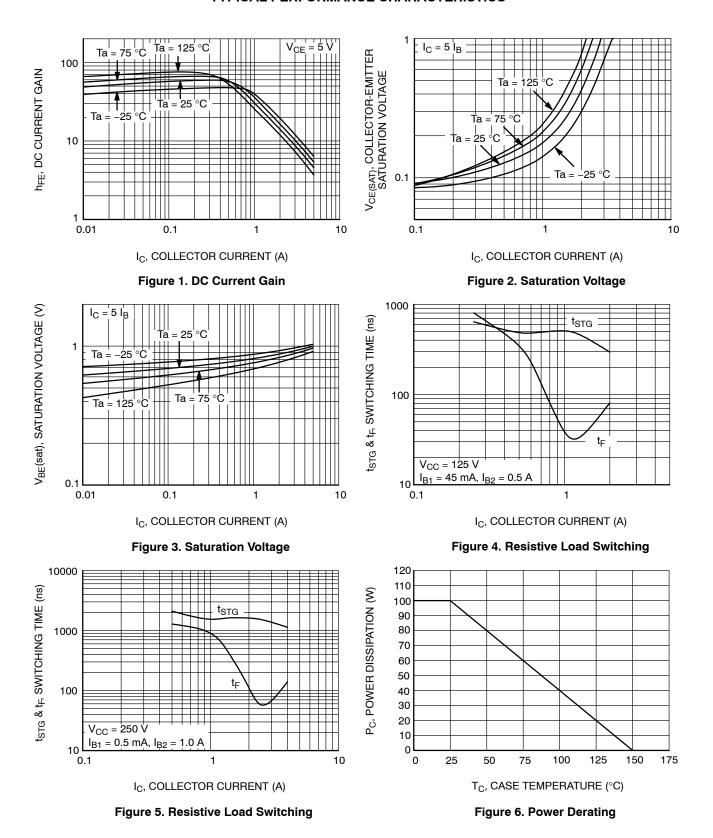
Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 500 μA, I <sub>E</sub> = 0	1050	-	-	V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 5 mA, I <sub>B</sub> = 0	400	-	-	V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 500 μA, I <sub>C</sub> = 0	14	-	-	V
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 10 mA	10	-	-	
		V <sub>CE</sub> = 3 V, I <sub>C</sub> = 0.8 A	20	-	40	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1 A, I <sub>B</sub> = 0.2 A	-	0.17	0.50	V
		I <sub>C</sub> = 3.5 A, I <sub>B</sub> = 1.0 A	-	-	1.5	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 3.5 A, I <sub>B</sub> = 1.0 A	-	-	1.2	V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10 V, f = 1 MHz	-	45	-	pF
t <sub>ON</sub>	Turn-On Time	V <sub>CC</sub> = 125 V, I <sub>C</sub> = 0.5 A,	-	-	1.0	μs
tstg	Storage Time	$I_{B1}$ = 45 mA, $I_{B2}$ = -0.5 A, $I_{L}$ = 250 Ω	_	-	1.2	μs
t <sub>F</sub>	Fall Time		_	0.3	-	μs
t <sub>ON</sub>	Turn-On Time	V <sub>CC</sub> = 250 V, I <sub>C</sub> = 2.5 A,	-	-	2.0	μs
t <sub>STG</sub>	Storage Time	$I_{B1} = 0.5 \text{ A}, I_{B2} = -1.0 \text{ A},$ $R_L = 100 \Omega$	-	_	2.5	μs
t <sub>F</sub>	Fall Time		-	_	0.3	μs
EAS	Avalanche Energy	L = 2 mH	6	-	-	mJ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse test: pulse width  $\leq 300~\mu s$ , duty cycle  $\leq 2\%$ 

#### FJB5555

#### TYPICAL PERFORMANCE CHARACTERISTICS



#### FJB5555

# TYPICAL PERFORMANCE CHARACTERISTICS (continued)

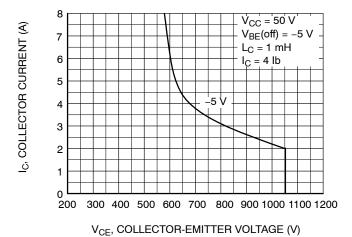


Figure 7. Reverse Bias Safe Operating





0.653

2x 0.063

#### D<sup>2</sup>PAK-3 (TO-263, 3-LEAD) CASE 418AJ ISSUE F

**DATE 11 MAR 2021** 



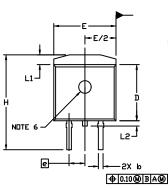
0.366

0.169

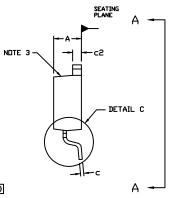
0.100 PITCH

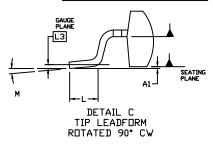
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: INCHES
- 3. CHAMFER OPTIONAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.005 PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE DUTERMOST EXTREMES OF THE PLASTIC BODY AT DATUM H.
- 5. THERMAL PAD CONTOUR IS OPTIONAL WITHIN DIMENSIONS E, L1, D1, AND E1.
- 6. OPTIONAL MOLD FEATURE.
- 7. ①,② ... OPTIONAL CONSTRUCTION FEATURE CALL DUTS.

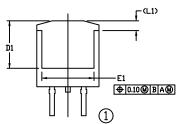
	INCHES		MILLIN	ETERS	
DIM	MIN.	MAX.	MIN.	MAX.	
Α	0.160	0.190	4.06	4.83	
A1	0.000	0.010	0.00	0.25	
b	0.020	0.039	0.51	0.99	
c	0.012	0.029	0.30	0.74	
c2	0.045	0.065	1.14	1.65	
D	0.330	0.380	8.38	9.65	
D1	0.260		6.60		
E	0.380	0.420	9.65	10.67	
E1	0.245		6.22		
e	0.100 BSC		2.54 BSC		
Ξ	0.575	0.625	14.60	15.88	
L	0.070	0.110	1.78	2.79	
L1		0.066		1.68	
L2		0.070		1.78	
L3	0.010 BSC		SC 0.25 BSC		
М	0*	8*	0*	8•	



RECOMMENDED MOUNTING FOOTPRINT



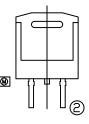




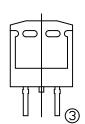
XXXXXXXX

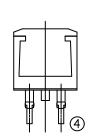
**AWLYWWG** 

VIEW A-A



**GENERIC MARKING DIAGRAMS\*** 





VIEW A-A

OPTIONAL CONSTRUCTIONS

XXXXXX

**XXYMW** 

SSG

**AYWW** 

XXXXXXXXX

Rectifier

**AKA** 

## XXXXXX = Specific Device Code

A = Assembly Location

WL = Wafer Lot Y = Year

WW = Work Week

W = Week Code (SSG)

M = Month Code (SSG)

G = Pb-Free Package

AKA = Polarity Indicator

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present. Some products may not follow the Generic Marking.

# DOCUMENT NUMBER:

98AON56370E

XXXXXXXX

**AYWW** 

Standard

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DESCRIPTION:

D<sup>2</sup>PAK-3 (TO-263, 3-LEAD)

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